74HC2G66-Q100; 74HCT2G66-Q100 Dual single-pole single-throw analog switch

Rev. 1 — 18 November 2013

Product data sheet

General description 1.

The 74HC2G66-Q100; 74HCT2G66-Q100 is a dual single pole, single-throw analog switch. Each switch has two input/output terminals (nY and nZ) and a digital enable input (nE). When nE is LOW, the analog switch is turned off. Inputs include clamp diodes that enable the use of current limiting resistors to interface inputs to voltages in excess of V_{CC} .

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

Features and benefits 2.

- Automotive product qualification in accordance with AEC-Q100 (Grade 1) Specified from –40 °C to +85 °C and from –40 °C to +125 °C
- Wide supply voltage range from 2.0 V to 10.0 V for 74HC2G66-Q100
- Very low ON resistance:
 - 41 Ω (typ.) at V_{CC} = 4.5 V
 - 30 Ω (typ.) at V_{CC} = 6.0 V
 - 21 Ω (typ.) at V_{CC} = 9.0 V
- High noise immunity
- Low power dissipation
- 25 mA continuous switch current
- Multiple package options
- ESD protection:
 - MIL-STD-883, method 3015 exceeds 2000 V
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)



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3. Ordering information

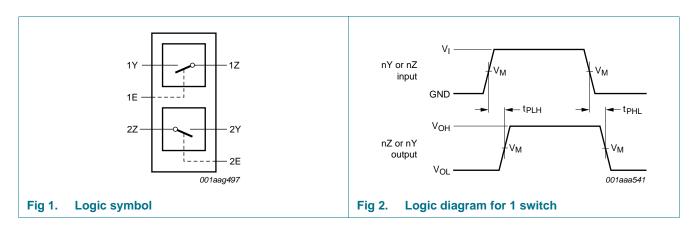
Table 1. Ordering information										
Type number	Package									
	Temperature range	Name	Description	Version						
74HC2G66DP-Q100	–40 °C to +125 °C	TSSOP8	plastic thin shrink small outline package; 8	SOT505-2						
74HCT2G66DP-Q100			leads; body width 3 mm; lead length 0.5 mm							
74HC2G66DC-Q100	–40 °C to +125 °C	VSSOP8	plastic very thin shrink small outline package; 8	SOT765-1						
74HCT2G66DC-Q100	_		leads; body width 2.3 mm							

4. Marking

Table 2. Marking codes	
Type number	Marking ^[1]
74HC2G66DP-Q100	H66
74HCT2G66DP-Q100	T66
74HC2G66DC-Q100	H66
74HCT2G66DC-Q100	T66

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

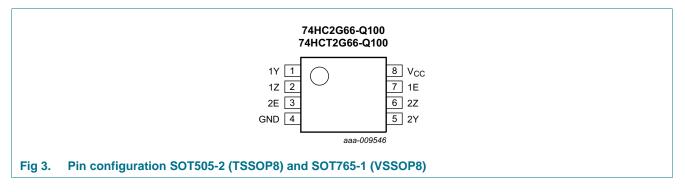
5. Functional diagram



Dual single-pole single-throw analog switch

6. Pinning information

6.1 Pinning



6.2 Pin description

Table 3.	Pin description	
Symbol	Pin	Description
1Y, 2Y	1, 5	independent input or output
1Z, 2Z	2, 6	independent input or output
GND	4	ground (0 V)
1E, 2E	7, 3	enable input (active HIGH)
V _{CC}	8	supply voltage

7. Functional description

Table 4.Function table^[1]

Input nE	Switch
L	OFF
Н	ON

[1] H = HIGH voltage level; L = LOW voltage level.

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8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+11.0	V
I _{IK}	input clamping current	$V_{\rm I} < -0.5$ V or $V_{\rm I}$ > $V_{\rm CC}$ + 0.5 V	<u>[1]</u> -	±20	mA
I _{SK}	switch clamping current	$V_{\rm I} < -0.5$ V or $V_{\rm I}$ > $V_{\rm CC}$ + 0.5 V	<u>[1]</u> -	±20	mA
I _{SW}	switch current	V_{SW} > –0.5 V or V_{SW} < V_{CC} + 0.5 V	-	±20	mA
I _{CC}	supply current		-	30	mA
I _{GND}	ground current		-30	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 \ ^{\circ}C \text{ to } +125 \ ^{\circ}C$			
		per package	[2] _	300	mW
		per switch	[2] _	100	mW
-					

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For TSSOP8 packages: above 55 °C the value of Ptot derates linearly with 2.5 mW/K.

For VSSOP8 packages: above 110 °C the value of Ptot derates linearly with 8.0 mW/K.

9. Recommended operating conditions

Table 6. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).^[1]

Symbol	I Parameter Conditions		74H	C2G66-0	2100	74HCT2G66-Q100			Unit
			Min	Тур	Max	Min	Тур	Max	
V _{CC}	supply voltage		2.0	5.0	10.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V _{CC}	0	-	V_{CC}	V
Vo	output voltage		0	-	V _{CC}	0	-	V_{CC}	V
V _{SW}	switch voltage		0	-	V _{CC}	0	-	V_{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
$\Delta t / \Delta V$	input transition rise	$V_{CC} = 2.0 V$	-	-	625	-	-	-	ns/V
	and fall rate	$V_{CC} = 4.5 V$	-	1.67	139	-	1.67	139	ns/V
		$V_{CC} = 6.0 V$	-	-	83	-	-	-	ns/V
		V _{CC} = 10.0 V	-	-	35	-	-	-	ns/V

[1] To avoid drawing V_{CC} current out of pin nZ, when switch current flows in pin nY, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into pin nZ, no V_{CC} current flows out of terminal nY. In this case, there is no limit for the voltage drop across the switch, but the voltage at pins nY and nZ may not exceed V_{CC} or GND.

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10. Static characteristics

Table 7. Static characteristics

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40	°C to +8	5 °C	–40 °C to +125 °C		
			Min	Typ <mark>[1]</mark>	Max	Min	Max	
4HC2G	66-Q100							
/ _{IH}	HIGH-level	$V_{CC} = 2.0 V$	1.5	1.2	-	1.5	-	V
	input voltage	$V_{CC} = 4.5 V$	3.15	2.4	-	3.15	-	V
		$V_{CC} = 6.0 V$	4.2	3.2	-	4.2	-	V
		V _{CC} = 9.0 V	6.3	4.7	-	6.3	-	V
/ _{IL}	LOW-level	$V_{CC} = 2.0 V$	-	0.8	0.5	-	0.5	V
	input voltage	$V_{CC} = 4.5 V$	-	2.1	1.35	-	1.35	V
		$V_{CC} = 6.0 V$	-	2.8	1.8	-	1.8	V
		$V_{CC} = 9.0 V$	-	4.3	2.7	-	2.7	V
I	input leakage current	nE; $V_I = V_{CC}$ or GND						
		$V_{CC} = 6.0 V$	-	-	±0.1	-	±0.1	μA
		V _{CC} = 9.0 V	-	-	±0.2	-	±0.2	μA
S(OFF)	OFF-state leakage current	nY or nZ; V_{CC} = 9.0 V; see <u>Figure 4</u>	-	0.1	1.0	-	1.0	μA
S(ON)	ON-state leakage current	nY or nZ; V_{CC} = 9.0 V; see <u>Figure 5</u>	-	0.1	1.0	-	1.0	μA
СС	supply current	nE, nY and nZ = V_{CC} or GND						
		$V_{CC} = 6.0 V$	-	-	10	-	20	μA
		V _{CC} = 9.0 V	-	-	20	-	40	μΑ
Ci	input capacitance		-	3.5	-	-	-	pF
PD	power dissipation capacitance		-	9	-	-	-	pF
C _{S(ON)}	ON-state capacitance		-	8	-	-	-	pF
4HCT2	G66-Q100							
∕ін	HIGH-level input voltage	V_{CC} = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	V
/ _{IL}	LOW-level input voltage	V_{CC} = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	V
	input leakage current	nE; $V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±1.0	-	±1.0	μA
S(OFF)	OFF-state leakage current	nY or nZ; V_{CC} = 5.5 V; see Figure 4	-	0.1	1.0	-	1.0	μA
S(ON)	ON-state leakage current	nY or nZ; V_{CC} = 5.5 V; see Figure 5	-	0.1	1.0	-	1.0	μA
CC	supply current	nE, nY and nZ = V_{CC} or GND; V_{CC} = 4.5 V to 5.5 V	-	-	10	-	20	μA
Alcc	additional supply current	$nE = V_{CC} - 2.1 \text{ V}; I_0 = 0 \text{ A};$ $V_{CC} = 4.5 \text{ V}$ to 5.5 V;	-	-	375	-	410	μA

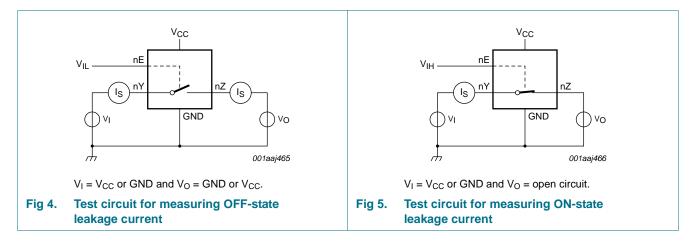
Dual single-pole single-throw analog switch

Table 7.Static characteristics ... continuedVoltages are referenced to GND (ground = 0.V)

vonages	are referenced to GND (g	f(Ound = 0 v).							
Symbol	Parameter	Conditions		–40 °C to +85 °C			–40 °C to	Unit	
			Mi	in	Typ <mark>[1]</mark>	Max	Min	Max	
CI	input capacitance		-	-	3.5	-	-	-	pF
C _{PD}	power dissipation capacitance		-	-	9	-	-	-	pF
C _{S(ON)}	ON-state capacitance		-	-	8	-	-	-	pF

[1] Typical values are measured at $T_{amb} = 25 \ ^{\circ}C$.

10.1 Test circuits



Dual single-pole single-throw analog switch

10.2 ON resistance

Table 8. ON resistance for 74HC2G66 and 74HCT2G66

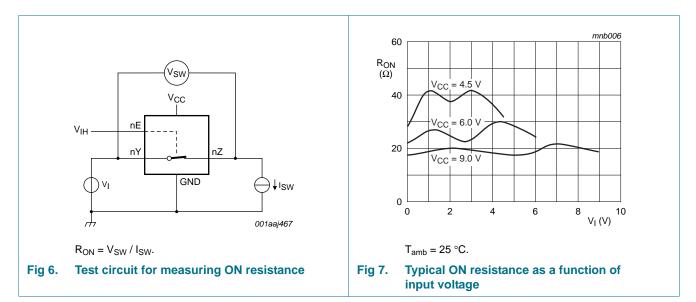
At recommended operating conditions; voltages are referenced to GND (ground 0 V); for graph see Figure 7.

Symbol	Parameter	Conditions	-40	°C to +8	S5 ℃) °C 25 °C	Unit
			Min	Typ ^[2]	Max	Min	Max	
74HC2G	66-Q100[<u>1]</u>							
R _{ON(peak)}	ON resistance (peak)	$V_I = GND$ to V_{CC} ; see <u>Figure 6</u> and <u>7</u>						
		$I_{SW} = 0.1 \text{ mA}; V_{CC} = 2.0 \text{ V}$	-	250	-	-	-	Ω
		I_{SW} = 1.0 mA; V_{CC} = 4.5 V	-	41	118	-	142	Ω
		I_{SW} = 1.0 mA; V_{CC} = 6.0 V	-	30	105	-	126	Ω
		I_{SW} = 1.0 mA; V_{CC} = 9.0 V	-	21	88	-	105	Ω
R _{ON(rail)}	ON resistance (rail)	$V_I = GND$; see <u>Figure 6</u> and <u>7</u>						
		$I_{SW} = 0.1 \text{ mA}; V_{CC} = 2.0 \text{ V}$	-	65	-	-	-	Ω
		I_{SW} = 1.0 mA; V_{CC} = 4.5 V	-	28	95	-	115	Ω
		I_{SW} = 1.0 mA; V_{CC} = 6.0 V	-	22	82	-	100	Ω
		I_{SW} = 1.0 mA; V_{CC} = 9.0 V	-	18	70	-	80	Ω
		$V_I = V_{CC}$; see <u>Figure 6</u> and <u>7</u>						
		$I_{SW} = 0.1 \text{ mA}; V_{CC} = 2.0 \text{ V}$	-	65	-	-	-	Ω
		I_{SW} = 1.0 mA; V_{CC} = 4.5 V	-	31	106	-	128	Ω
		I_{SW} = 1.0 mA; V_{CC} = 6.0 V	-	23	94	-	113	Ω
		I_{SW} = 1.0 mA; V_{CC} = 9.0 V	-	19	78	-	95	Ω
∆R _{ON}	ON resistance mismatch	$V_I = V_{CC}$ to GND; see <u>Figure 6</u> and <u>7</u>						
	between channels	$V_{CC} = 4.5 V$	-	5	-	-	-	Ω
		$V_{CC} = 6.0 V$	-	4	-	-	-	Ω
		$V_{CC} = 9.0 V$	-	3	-	-	-	Ω
74HCT26	66-Q100							
R _{ON(peak)}	ON resistance (peak)	$V_I = GND$ to V_{CC} ; see <u>Figure 6</u> and <u>7</u>						
		I_{SW} = 1.0 mA; V_{CC} = 4.5 V	-	41	118	-	142	Ω
R _{ON(rail)}	ON resistance (rail)	$V_I = GND$; see <u>Figure 6</u> and <u>7</u>						
		I_{SW} = 1.0 mA; V_{CC} = 4.5 V	-	28	95	-	115	Ω
		$V_I = V_{CC}$; see <u>Figure 6</u> and <u>7</u>						
		I_{SW} = 1.0 mA; V_{CC} = 4.5 V	-	31	106	-	128	Ω
ΔR_{ON}	ON resistance mismatch	$V_I = V_{CC}$ to GND; see <u>Figure 6</u> and <u>7</u>						
	between channels	$V_{CC} = 4.5 V$	-	5	-	-	-	Ω

[1] At supply voltages approaching 2 V, the ON resistance becomes extremely non-linear. Therefore it is recommended that these devices be used to transmit digital signals only, when using this supply voltage.

[2] Typical values are measured at T_{amb} = 25 °C.

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10.3 ON resistance test circuit and graphs

11. Dynamic characteristics

Table 9. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit, see Figure 10.

Symbol	Parameter	Conditions		-40	°C to +85	5 °C	–40 °C t	o +125 °C	Unit
			-	Min	Typ <mark>[1]</mark>	Max	Min	Max	
74HC2G	66-Q100								
t _{pd}	propagation delay	nY to nZ or nZ to nY; $R_L = \infty \Omega$; see Figure 8	[2]						
		$V_{CC} = 2.0 V$		-	6.5	65	-	80	ns
		$V_{CC} = 4.5 V$		-	2	13	-	15	ns
		$V_{CC} = 6.0 V$		-	1.5	11	-	14	ns
		$V_{CC} = 9.0 V$		-	1.2	10	-	12	ns
t _{en}	enable time	nE to nY or nZ; see <u>Figure 9</u>	[2]						
		$V_{CC} = 2.0 V$		-	40	125	-	150	ns
		$V_{CC} = 4.5 V$		-	12	29	-	30	ns
		$V_{CC} = 6.0 V$		-	10	21	-	26	ns
		$V_{CC} = 9.0 V$		-	7	16	-	20	ns
t _{dis}	disable time	nE to nY or nZ; see <u>Figure 9</u>	[2]						
		$V_{CC} = 2.0 V$		-	21	145	-	175	ns
		$V_{CC} = 4.5 V$		-	12	29	-	35	ns
		$V_{CC} = 6.0 V$		-	11	28	-	33	ns
		$V_{CC} = 9.0 V$		-	10	23	-	27	ns
C _{PD}	power dissipation capacitance	$V_1 = GND$ to V_{CC}	<u>[3]</u>	-	9	-	-	-	pF

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Symbol	Parameter	Conditions		-40) °C to +85	5°C	–40 °C t	o +125 °C	Unit
				Min	Typ <mark>[1]</mark>	Max	Min	Max	
74HCT2	G66-Q100								
t _{pd}	propagation delay	nY to nZ or nZ to nY; $R_L = \infty \Omega$; see Figure 8	[2]						
		$V_{CC} = 4.5 V$		-	2	15	-	18	ns
t _{en}	enable time	nE to nY or nZ; see <u>Figure 9</u>	[2]						
		$V_{CC} = 4.5 V$		-	13	30	-	36	ns
t _{dis}	disable time	nE to nY or nZ; see <u>Figure 9</u>	[2]						
		$V_{CC} = 4.5 V$		-	13	44	-	53	ns
C _{PD}	power dissipation capacitance	V_{I} = GND to $V_{CC}-1.5~V$	<u>[3]</u>	-	9	-	-	-	pF

Table 9. Dynamic characteristics ...continued

[1] All typical values are measured at T_{amb} = 25 °C.

[3] C_{PD} is used to determine the dynamic power dissipation P_D (μ W).

 $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} + \Sigma((C_{L} \times C_{SW}) \times V_{CC}^{2} \times f_{o}) \text{ where:}$

 f_i = input frequency in MHz;

f_o = output frequency in MHz;

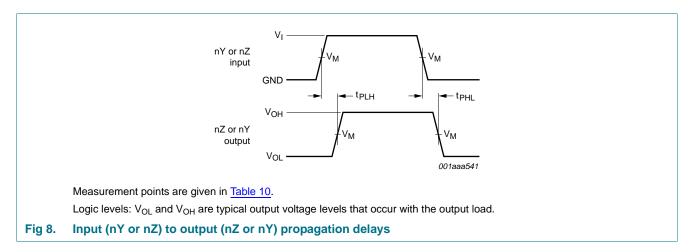
 C_L = output load capacitance in pF;

 C_{SW} = maximum switch capacitance in pF (see Table 7);

V_{CC} = supply voltage in volts;

 $\Sigma((C_L \times C_{SW}) \times V_{CC}^2 \times f_o) = \text{sum of outputs.}$

11.1 Waveforms and test circuit



Dual single-pole single-throw analog switch

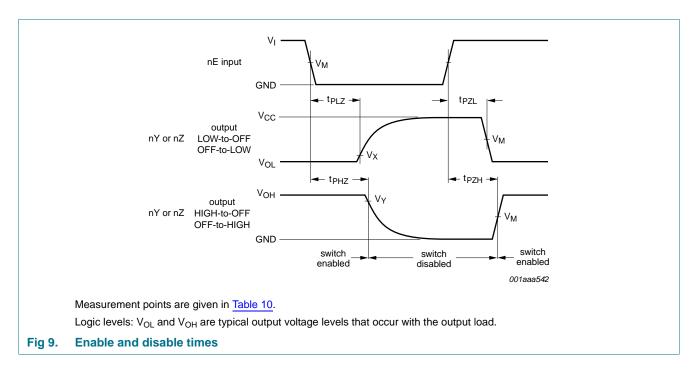


Table 10.Measurement points

Туре	Input	Output				
	V _M	V _M	V _X	V _Y		
74HC2G66-Q100	0.5V _{CC}	0.5V _{CC}	V _{OL} + 10 %	V _{OH} – 10 %		
74HCT2G66-Q100	1.3 V	1.3 V	V _{OL} + 10 %	V _{OH} – 10 %		

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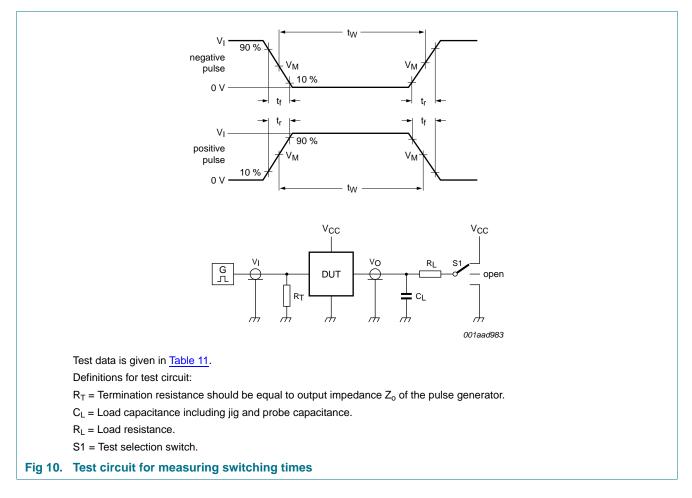


Table 11. Test data

Туре	Input		Load		S1 position		
	VI	t _r , t _f [1]	CL	RL	t _{PHL} , t _{PLH}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
74HC2G66-Q100	GND to V_{CC}	6 ns	50 pF	1 kΩ	open	GND	V _{CC}
74HCT2G66-Q100	GND to 3 V	6 ns	50 pF	1 kΩ	open	GND	V _{CC}

[1] There is no constraint on t_r , t_f with a 50 % duty factor when measuring f_{max} .

Dual single-pole single-throw analog switch

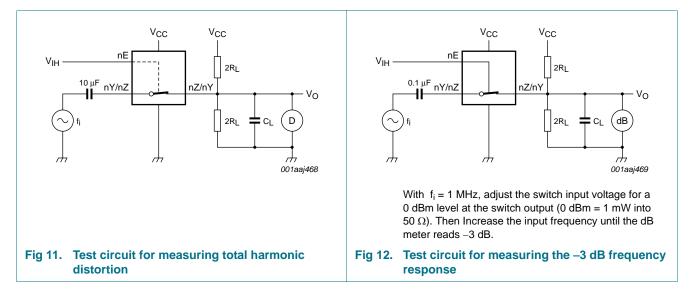
11.2 Additional dynamic characteristics

Table 12. Additional dynamic characteristics for 74HC2G66 and 74HCT2G66

GND = 0 V; $t_r = t_f = 6.0$ ns; $C_L = 50$ pF; unless otherwise specified. All typical values are measured at $T_{amb} = 25$ °C.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
THD	total harmonic distortion	$f_i = 1 \text{ kHz}; \text{ R}_L = 10 \text{ k}\Omega; \text{ see } \frac{\text{Figure } 11}{100000000000000000000000000000000$				%
		V _{CC} = 4.5 V; V _I = 4.0 V (p-p)	-	0.04	-	%
		V _{CC} = 9.0 V; V _I = 8.0 V (p-p)	-	0.02	-	%
		$f_i = 10 \text{ kHz}; \text{ R}_L = 10 \text{ k}\Omega; \text{ see } \frac{\text{Figure 11}}{1000000000000000000000000000000000$				
		V _{CC} = 4.5 V; V _I = 4.0 V (p-p)	-	0.12	-	%
		$V_{CC} = 9.0 \text{ V}; \text{ V}_{I} = 8.0 \text{ V} \text{ (p-p)}$	-	0.06	-	%
f _(-3dB)	–3 dB frequency response	$R_L = 50 \Omega$; $C_L = 10 pF$; see <u>Figure 12</u> and <u>13</u>				
		$V_{CC} = 4.5 V$	-	180	-	MHz
		$V_{CC} = 9.0 V$	-	200	-	MHz
α_{iso}	isolation (OFF-state)	R_L = 600 Ω; f _i = 1 MHz; see <u>Figure 14</u> and <u>15</u>				
		$V_{CC} = 4.5 V$	-	-50	-	dB
		$V_{CC} = 9.0 V$	-	-50	-	dB
V _{ct}	crosstalk voltage	between digital input and switch (peak to peak value); $R_L = 600 \Omega$; $f_i = 1 MHz$; see Figure 16				
		$V_{CC} = 4.5 V$	-	110	-	mV
		$V_{CC} = 9.0 V$	-	220	-	mV
Xtalk	crosstalk	between switches; $R_L = 600 \Omega$; $f_i = 1 MHz$; see <u>Figure 17</u>				
		$V_{CC} = 4.5 V$	-	-60	-	dB
		$V_{CC} = 9.0 V$	-	-60	-	dB

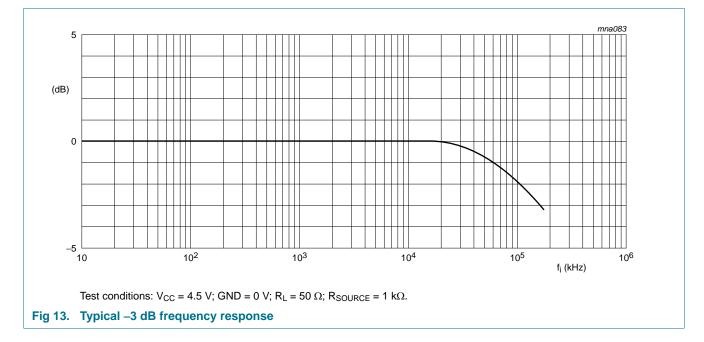
11.3 Test circuits and graphs

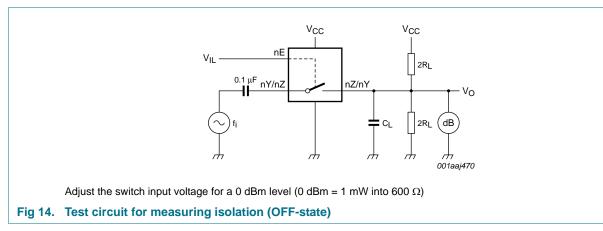


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74HC2G66-Q100; 74HCT2G66-Q100

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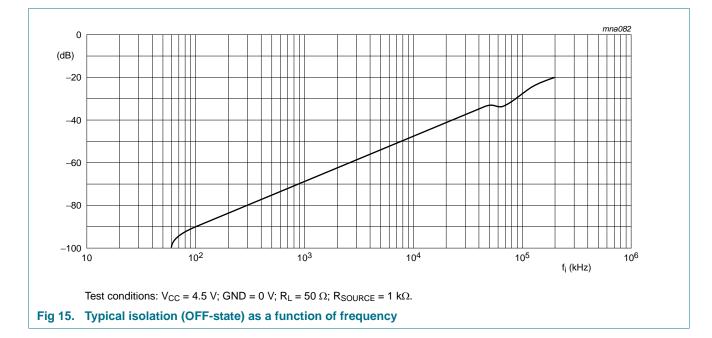


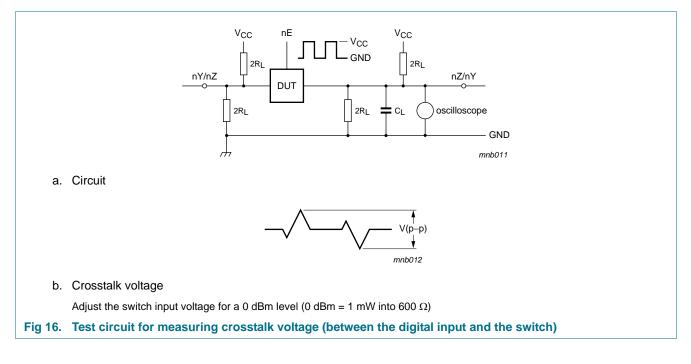
74HC_HCT2G66_Q100

NXP Semiconductors

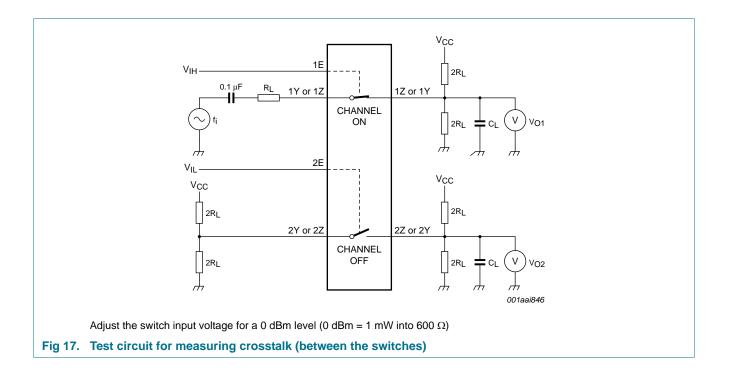
74HC2G66-Q100; 74HCT2G66-Q100

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Dual single-pole single-throw analog switch



Dual single-pole single-throw analog switch

12. Package outline

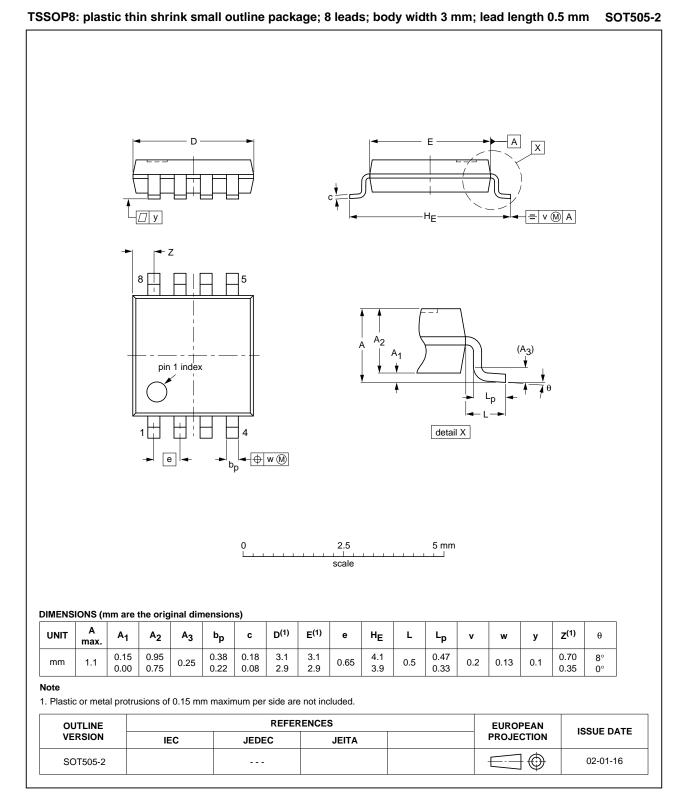


Fig 18. Package outline SOT505-2 (TSSOP8)

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74HC_HCT2G66_Q100

Dual single-pole single-throw analog switch

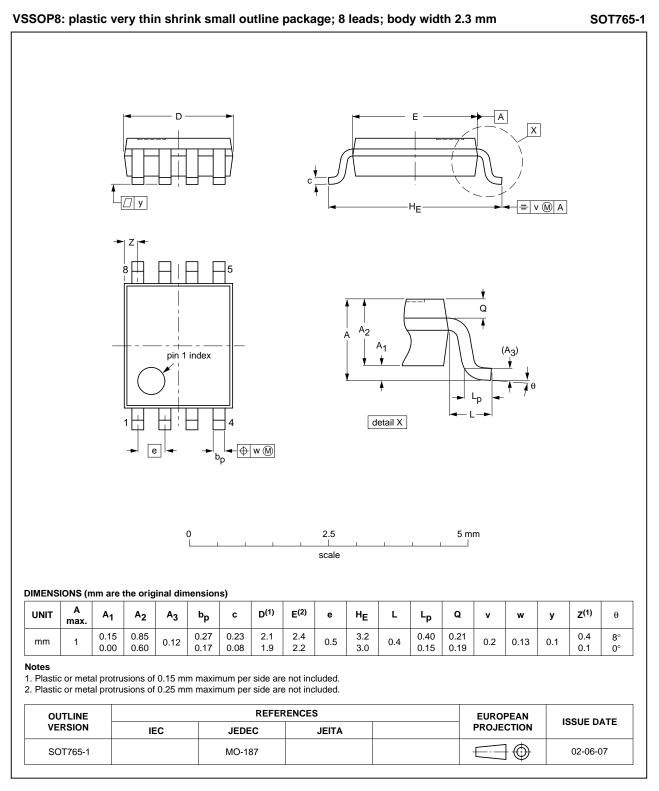


Fig 19. Package outline SOT765-1 (VSSOP8)

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13. Abbreviations

Table 13. Abbreviations			
Acronym	Description		
CMOS	Complementary Metal-Oxide Semiconductor		
ESD	ElectroStatic Discharge		
HBM	Human Body Model		
MIL	Military		
MM	Machine Model		
DUT	Device Under Test		

14. Revision history

Table 14. Revision history				
Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT2G66_Q100 v.1	20131118	Product data sheet	-	-

74HC_HCT2G66_Q100

Dual single-pole single-throw analog switch

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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